

## 1. General Description

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The EM74LVC1G14 is a single inverter with Schmitt-trigger inputs. Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in mixed 3.3 V and 5 V environments. This device is fully specified for partial power down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

## 2. Features and Benefits

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- Wide supply voltage range from 1.65 V to 5.5 V
- Overvoltage tolerant inputs to 5.5 V
- High noise immunity
- $\pm 24$  mA output drive ( $V_{CC} = 3.0$  V)
- CMOS low power dissipation
- Latch-up performance exceeds 100 mA
- Direct interface with TTL levels
- $I_{OFF}$  circuitry provides partial Power-down mode operation
- Unlimited rise and fall times
- Complies with JEDEC standard:
  - JESD8-7 (1.65 V to 1.95 V)
  - JESD8-5 (2.3 V to 2.7 V)
  - JESD8C (2.7 V to 3.6 V)
  - JESD36 (4.5 V to 5.5 V)
- ESD protection:
  - HBM ANSI/ESDA/JEDEC JS-001 Class 3B exceeds 8000 V
  - MM JESD22-A115C Class C exceeds 550 V
  - CDM ANSI/ESDA/JEDEC JS-002 Class C3 exceeds 2000 V
- Multiple package options

## EM74LVC1G14

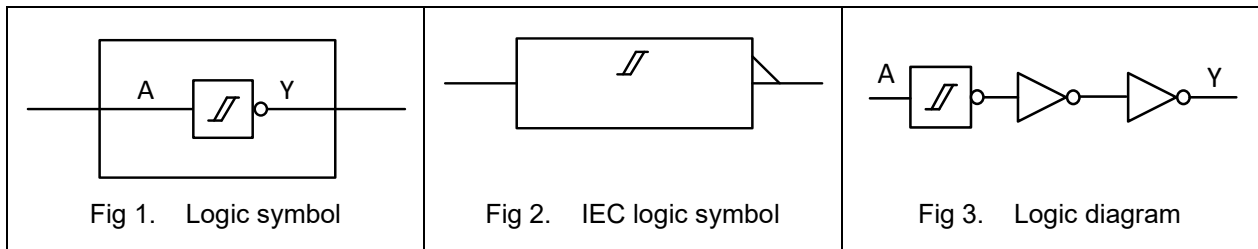
Single Schmitt trigger inverter

### 3. Ordering Information

Table 1. Ordering information

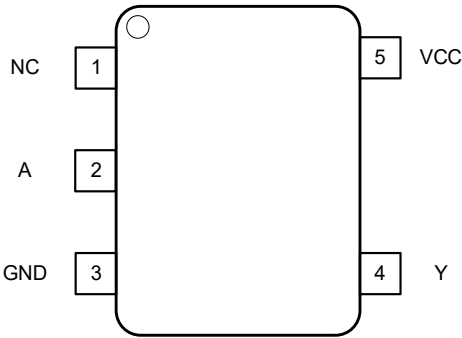
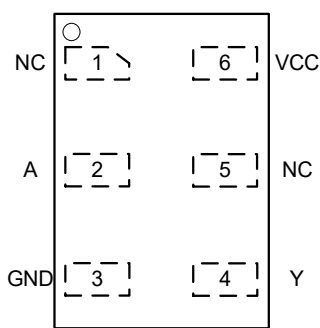
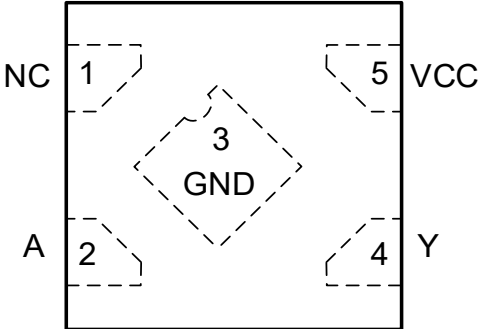
| Type number   | Topside marking | Package       |                                                                    | Quantity |
|---------------|-----------------|---------------|--------------------------------------------------------------------|----------|
|               |                 | Name          | Description                                                        |          |
| EM74LVC1G14GV | VAYW            | SOT23-5L      | SOT23 package, 5 pins<br>2.92 mm × 1.6 mm; 1.25 mm (Max) height    | 3000     |
| EM74LVC1G14GW | VAYW            | SOT353        | SOT353 package, 5 pins<br>2.1 mm × 1.25 mm; 1.1 mm (Max) height    | 3000     |
| EM74LVC1G14GS | VA              | DFN1x1-6L     | DFN1×1 package, 6 pins<br>1 mm × 1 mm; 0.42 mm (Max) height        | 3000     |
| EM74LVC1G14GM | VAYW            | DFN1x1.45-6L  | DFN1.45×1 package, 6 pins<br>1.45 mm × 1 mm; 0.6 mm (Max) height   | 3000     |
| EM74LVC1G14GX | VA              | DFN0.8x0.8-4L | DFN0.8×0.8 package, 5 pins<br>0.8 mm × 0.8 mm; 0.4 mm (Max) height | 3000     |

### 4. Function Diagram



## 5. Pinning Information

### 5.1. Pin map

|                                                                                                                                               |                                                                                                                                   |
|-----------------------------------------------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------|
|  <p>Fig 4. Top view pin configuration SOT23-5 and SOT353</p> |  <p>Fig 5. Top view pin configuration DFN6L</p> |
|  <p>Fig 6. Top view pin configuration DFN4L</p>             |                                                                                                                                   |

### 5.2. Pin description

**Table 2. Pin description**

| Symbol | Pin                       |       | Description    |
|--------|---------------------------|-------|----------------|
|        | SOT23-5, SOT353 and DFN4L | DFN6L |                |
| NC     | 1                         | 1, 5  | Not connected  |
| A      | 2                         | 2     | Data input     |
| GND    | 3                         | 3     | Ground (0V)    |
| Y      | 4                         | 4     | Data output    |
| VCC    | 5                         | 6     | Supply voltage |

## 6. Functional Description

**Table 3. Function table**

H = HIGH voltage level; L = LOW voltage level.

| Input | Output |
|-------|--------|
| A     | Y      |
| L     | H      |
| H     | L      |

## 7. Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

**Table 4. Absolute Maximum Ratings**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND.

| Symbol    | Parameter               | Conditions                          | Min  | Max            | Unit |
|-----------|-------------------------|-------------------------------------|------|----------------|------|
| $V_{CC}$  | supply voltage          |                                     | -0.5 | 6.5            | V    |
| $I_{IK}$  | input clamping current  | $V_I < 0$ V                         | -50  |                | mA   |
| $V_I$     | input voltage           | [1]                                 | -0.5 | 6.5            | V    |
| $I_{OK}$  | output clamping current | $V_O > V_{CC}$ or $V_O < 0$ V       |      | $\pm 50$       | mA   |
| $V_O$     | output voltage          | Active mode [1]                     | -0.5 | $V_{CC} + 0.5$ | V    |
|           |                         | Power-down mode; $V_{CC} = 0$ V [1] | -0.5 | 6.5            | V    |
| $I_O$     | output current          | $V_O = 0$ V to $V_{CC}$             |      | $\pm 50$       | mA   |
| $I_{CC}$  | supply current          |                                     |      | 100            | mA   |
| $I_{GND}$ | ground current          |                                     | -100 |                | mA   |
| $P_{tot}$ | total power dissipation | $T_{amb} = -40$ °C to $+125$ °C     |      | 250            | mW   |
| $T_{stg}$ | storage temperature     |                                     | -65  | 150            | °C   |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## 8. Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. EnergyMath does not recommend exceeding them or designing to Absolute Maximum Ratings.

**Table 5. Recommended Operating Conditions**

| Symbol           | Parameter           | Conditions                             | Min  | Typ | Max             | Unit |
|------------------|---------------------|----------------------------------------|------|-----|-----------------|------|
| V <sub>CC</sub>  | supply voltage      |                                        | 1.65 |     | 5.5             | V    |
| V <sub>I</sub>   | input voltage       |                                        | 0    |     | 5.5             | V    |
| V <sub>O</sub>   | output voltage      | Active mode                            | 0    |     | V <sub>CC</sub> | V    |
|                  |                     | Power-down mode; V <sub>CC</sub> = 0 V | 0    |     | 5.5             | V    |
| T <sub>amb</sub> | ambient temperature |                                        | -40  |     | 125             | °C   |

## 9.Static Characteristics

**Table 6. Static characteristics**

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

| Symbol          | Parameter                 | Conditions                                                                                                | -40 °C to +85 °C |           |         | -40 °C to +125 °C |         | Unit    |
|-----------------|---------------------------|-----------------------------------------------------------------------------------------------------------|------------------|-----------|---------|-------------------|---------|---------|
|                 |                           |                                                                                                           | Min              | Typ[1]    | Max     | Min               | Max     |         |
| $V_{OH}$        | HIGH-level output voltage | $V_I = V_{T+}$ or $V_{T-}$                                                                                |                  |           |         |                   |         |         |
|                 |                           | $I_O = -100\mu A$ ;<br>$V_{CC} = 1.65\text{ V to }5.5\text{ V}$                                           | $V_{CC} - 0.1$   |           |         | $V_{CC} - 0.1$    |         | V       |
|                 |                           | $I_O = -4\text{ mA}$ ; $V_{CC} = 1.65\text{ V}$                                                           | 1.2              | 1.54      |         | 0.95              |         | V       |
|                 |                           | $I_O = -8\text{ mA}$ ; $V_{CC} = 2.3\text{ V}$                                                            | 1.9              | 2.15      |         | 1.7               |         | V       |
|                 |                           | $I_O = -12\text{ mA}$ ; $V_{CC} = 2.7\text{ V}$                                                           | 2.2              | 2.50      |         | 1.9               |         | V       |
|                 |                           | $I_O = -24\text{ mA}$ ; $V_{CC} = 3.0\text{ V}$                                                           | 2.3              | 2.62      |         | 2.0               |         | V       |
|                 |                           | $I_O = -32\text{ mA}$ ; $V_{CC} = 4.5\text{ V}$                                                           | 3.8              | 4.11      |         | 3.4               |         | V       |
| $V_{OL}$        | LOW-level output voltage  | $V_I = V_{T+}$ or $V_{T-}$                                                                                |                  |           |         |                   |         |         |
|                 |                           | $I_O = 100\mu A$ ;<br>$V_{CC} = 1.65\text{ V to }5.5\text{ V}$                                            |                  |           | 0.10    |                   | 0.10    | V       |
|                 |                           | $I_O = 4\text{ mA}$ ; $V_{CC} = 1.65\text{ V}$                                                            |                  | 0.07      | 0.45    |                   | 0.70    | V       |
|                 |                           | $I_O = 8\text{ mA}$ ; $V_{CC} = 2.3\text{ V}$                                                             |                  | 0.12      | 0.30    |                   | 0.45    | V       |
|                 |                           | $I_O = 12\text{ mA}$ ; $V_{CC} = 2.7\text{ V}$                                                            |                  | 0.17      | 0.40    |                   | 0.60    | V       |
|                 |                           | $I_O = 24\text{ mA}$ ; $V_{CC} = 3.0\text{ V}$                                                            |                  | 0.33      | 0.55    |                   | 0.80    | V       |
|                 |                           | $I_O = 32\text{ mA}$ ; $V_{CC} = 4.5\text{ V}$                                                            |                  | 0.39      | 0.55    |                   | 0.80    | V       |
| $I_I$           | Input leakage current     | $V_I = 5.5\text{ V or GND}$ ;<br>$V_{CC} = 5.5\text{ V}$                                                  |                  | $\pm 0.1$ | $\pm 1$ |                   | $\pm 1$ | $\mu A$ |
| $I_{OFF}$       | power-off leakage current | $V_{CC} = 0\text{ V}$ ; $V_I$ or $V_O = 5.5\text{ V}$                                                     |                  | $\pm 0.1$ | $\pm 2$ |                   | $\pm 2$ | $\mu A$ |
| $I_{CC}$        | supply current            | $V_I = 5.5\text{ V or GND}$ ; $I_O = 0\text{ A}$ ;<br>$V_{CC} = 5.5\text{ V}$                             |                  | 0.1       | 4       |                   | 4       | $\mu A$ |
| $\Delta I_{CC}$ | additional supply current | per pin ; $V_{CC} = 2.3\text{ V to }5.5\text{ V}$ ;<br>$V_I = V_{CC} - 0.6\text{ V}$ ; $I_O = 0\text{ A}$ |                  | 5         | 500     |                   | 500     | $\mu A$ |
| $C_i$           | input capacitance         | $V_{CC} = 3.3\text{ V}$ ; $V_I = \text{GND to }V_{CC}$                                                    |                  | 5         |         |                   |         | pF      |

[1]All typical values are measured at  $V_{CC} = 3.3\text{ V}$  and  $T_{amb} = 25^\circ\text{C}$ .

## 10. Dynamic Characteristics

**Table 7. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 7.

| Symbol   | Parameter                     | Conditions                                                                 | -40 °C to +85 °C |        |      | -40 °C to +125 °C |      | Unit |
|----------|-------------------------------|----------------------------------------------------------------------------|------------------|--------|------|-------------------|------|------|
|          |                               |                                                                            | Min              | Typ[1] | Max  | Min               | Max  |      |
| $t_{pd}$ | propagation delay             | nA to nY; see Fig. 6 [2]                                                   |                  |        |      |                   |      |      |
|          |                               | $V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$                               | 4.0              | 10.6   | 19.5 | 4.0               | 19.8 | ns   |
|          |                               | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$                                 | 2.5              | 5.9    | 10.6 | 2.5               | 10.9 | ns   |
|          |                               | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$                                 | 2.0              | 4.3    | 7    | 2.0               | 7.5  | ns   |
|          |                               | $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$                                 | 1.5              | 2.9    | 4.8  | 1.5               | 5.0  | ns   |
| $C_{PD}$ | power dissipation capacitance | per buffer ; $V_I = \text{GND to } V_{CC}$ ;<br>$V_{CC} = 3.3\text{V}$ [3] |                  | 24     |      |                   |      | pF   |

[1] Typical values are measured at  $T_{amb} = 25 \text{ °C}$  and  $V_{CC} = 1.8 \text{ V}, 2.5 \text{ V}, 3.3 \text{ V}$  and  $5.0 \text{ V}$  respectively.

[2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

[3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$  where:

$f_i$  = input frequency in MHz;

$f_o$  = output frequency in MHz;

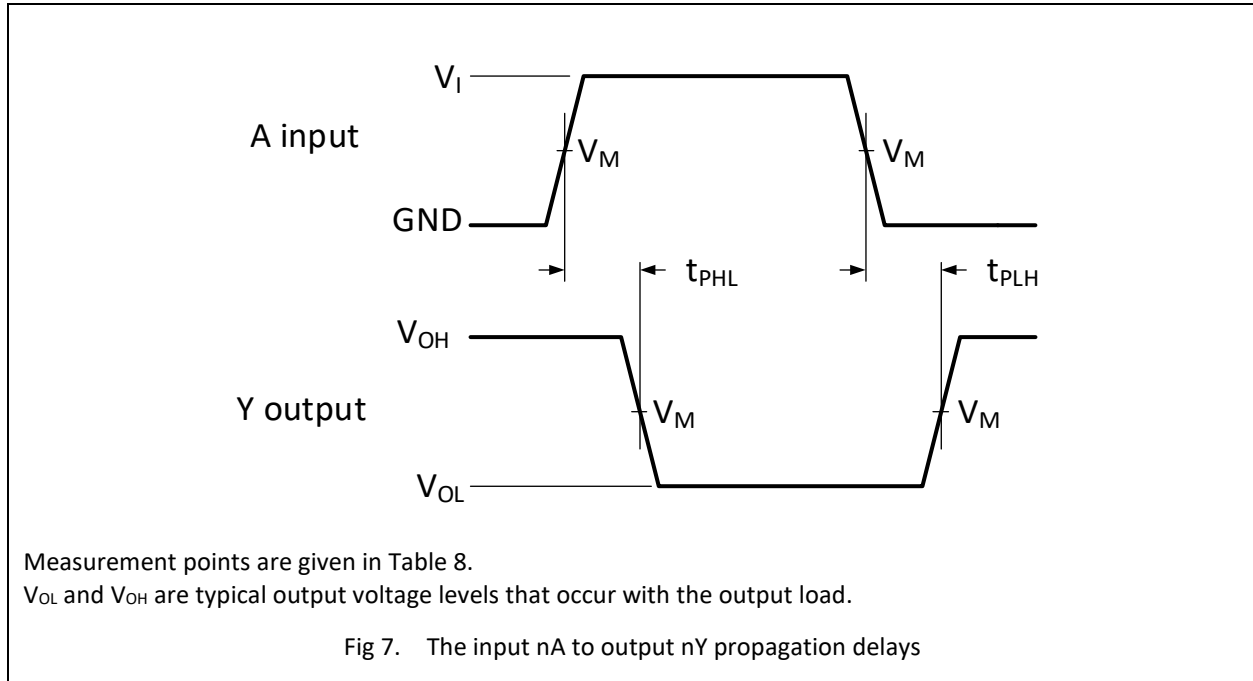
$C_L$  = output load capacitance in pF;

$V_{CC}$  = supply voltage in V;

$N$  = number of inputs switching;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

## 10.1. Waveforms and test circuit

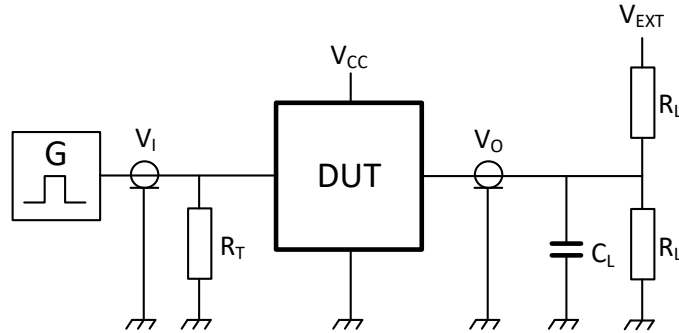


**Table 8. Measurement points**

| Supply voltage   | Input       | Output      |
|------------------|-------------|-------------|
| $V_{CC}$         | $V_M$       | $V_M$       |
| 1.65 V to 1.95 V | $0.5V_{CC}$ | $0.5V_{CC}$ |
| 2.3 V to 2.7 V   | $0.5V_{CC}$ | $0.5V_{CC}$ |
| 3.0 V to 3.6 V   | 1.5 V       | 1.5 V       |
| 4.5 V to 5.5 V   | $0.5V_{CC}$ | $0.5V_{CC}$ |

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### Single Schmitt trigger inverter



Test data is given in Table 9.

Definitions for test circuit:

$R_L$  = Load resistance.

$C_L$  = Load capacitance including jig and probe capacitance.

$R_T$  = Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator.

$V_{EXT}$  = External voltage for measuring switching times.

Fig 8. Test circuit for measuring switching times

Table 9. Test data

| Supply voltage   | Input    |               | Load  |              | $V_{EXT}$          |
|------------------|----------|---------------|-------|--------------|--------------------|
| $V_{CC}$         | $V_I$    | $t_r = t_f$   | $C_L$ | $R_L$        | $t_{PLH}, t_{PHL}$ |
| 1.65 V to 1.95 V | $V_{CC}$ | $\leq 2.0$ ns | 30 pF | 1 k $\Omega$ | open               |
| 2.3 V to 2.7 V   | $V_{CC}$ | $\leq 2.0$ ns | 30 pF | 500 $\Omega$ | open               |
| 3.0 V to 3.6 V   | 3 V      | $\leq 2.5$ ns | 50 pF | 500 $\Omega$ | open               |
| 4.5 V to 5.5 V   | $V_{CC}$ | $\leq 2.5$ ns | 50 pF | 500 $\Omega$ | open               |

# 11. Transfer Characteristics

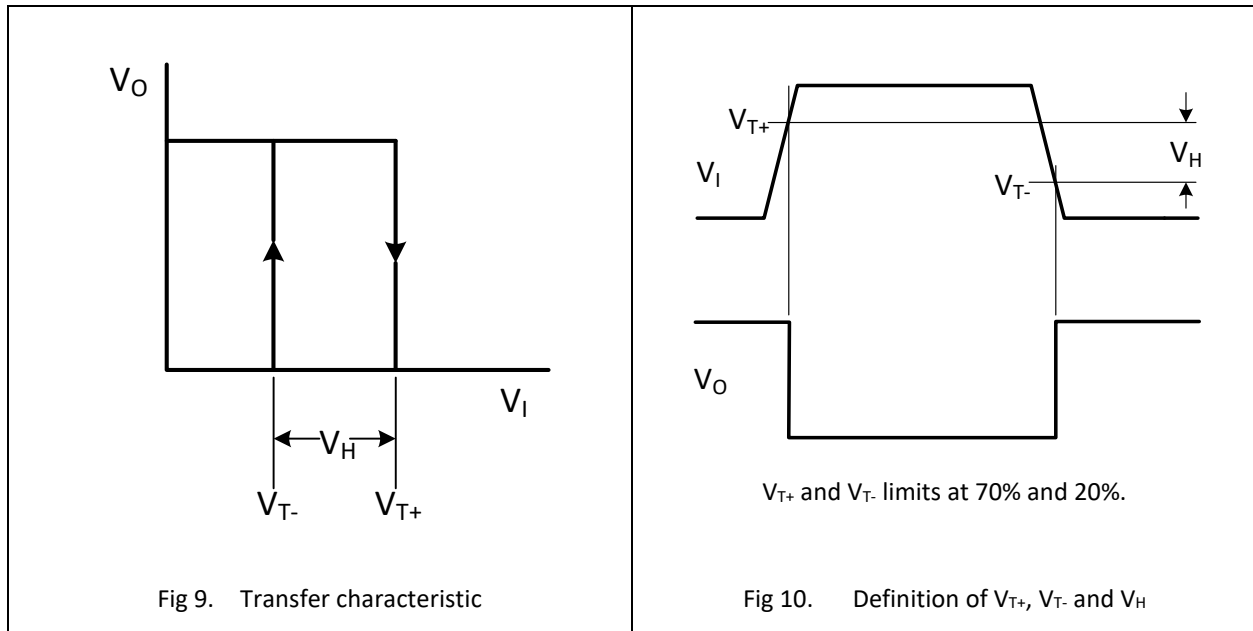
**Table 10. Transfer characteristics**

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

| Symbol   | Parameter                        | Conditions               | -40 °C to +85 °C |        |      | -40 °C to +125 °C |      | Unit |
|----------|----------------------------------|--------------------------|------------------|--------|------|-------------------|------|------|
|          |                                  |                          | Min              | Typ[1] | Max  | Min               | Max  |      |
| $V_{T+}$ | positive-going threshold voltage | see Fig. 9 and Fig. 10   |                  |        |      |                   |      |      |
|          |                                  | $V_{CC} = 1.8 \text{ V}$ | 0.82             | 1.0    | 1.14 | 0.79              | 1.14 | V    |
|          |                                  | $V_{CC} = 2.3 \text{ V}$ | 1.03             | 1.2    | 1.40 | 1.00              | 1.40 | V    |
|          |                                  | $V_{CC} = 3.0 \text{ V}$ | 1.29             | 1.5    | 1.71 | 1.26              | 1.71 | V    |
|          |                                  | $V_{CC} = 4.5 \text{ V}$ | 1.84             | 2.2    | 2.36 | 1.81              | 2.36 | V    |
|          |                                  | $V_{CC} = 5.5 \text{ V}$ | 2.19             | 2.6    | 2.79 | 2.16              | 2.79 | V    |
| $V_{T-}$ | negative-going threshold voltage | see Fig. 9 and Fig. 10   |                  |        |      |                   |      |      |
|          |                                  | $V_{CC} = 1.8 \text{ V}$ | 0.46             | 0.6    | 0.75 | 0.46              | 0.78 | V    |
|          |                                  | $V_{CC} = 2.3 \text{ V}$ | 0.65             | 0.7    | 0.96 | 0.65              | 0.99 | V    |
|          |                                  | $V_{CC} = 3.0 \text{ V}$ | 0.88             | 1.0    | 1.24 | 0.88              | 1.27 | V    |
|          |                                  | $V_{CC} = 4.5 \text{ V}$ | 1.32             | 1.6    | 1.84 | 1.32              | 1.87 | V    |
|          |                                  | $V_{CC} = 5.5 \text{ V}$ | 1.58             | 1.9    | 2.24 | 1.58              | 2.27 | V    |
| $V_H$    | hysteresis voltage               | see Fig. 9 and Fig. 10   |                  |        |      |                   |      |      |
|          |                                  | $V_{CC} = 1.8 \text{ V}$ | 0.26             | 0.5    | 0.62 | 0.19              | 0.62 | V    |
|          |                                  | $V_{CC} = 2.3 \text{ V}$ | 0.28             | 0.5    | 0.65 | 0.22              | 0.65 | V    |
|          |                                  | $V_{CC} = 3.0 \text{ V}$ | 0.31             | 0.6    | 0.7  | 0.25              | 0.7  | V    |
|          |                                  | $V_{CC} = 4.5 \text{ V}$ | 0.40             | 0.6    | 0.77 | 0.34              | 0.77 | V    |
|          |                                  | $V_{CC} = 5.5 \text{ V}$ | 0.47             | 0.6    | 0.88 | 0.41              | 0.88 | V    |

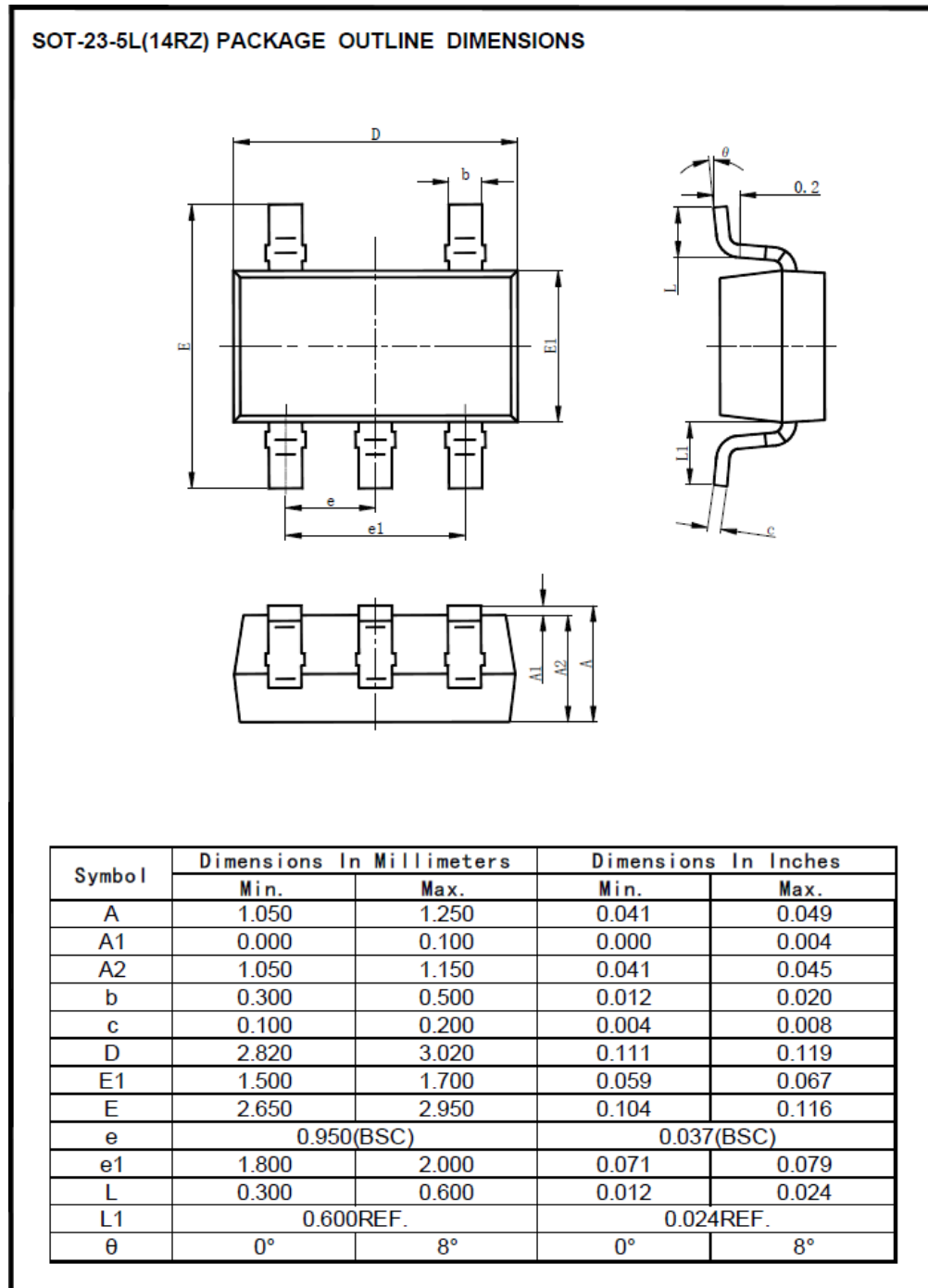
[1] Typical values are measured at  $T_{amb} = 25 \text{ °C}$ .

## 11.1. Waveforms transfer characteristics



## 12. Package Outline

SOT23-5L

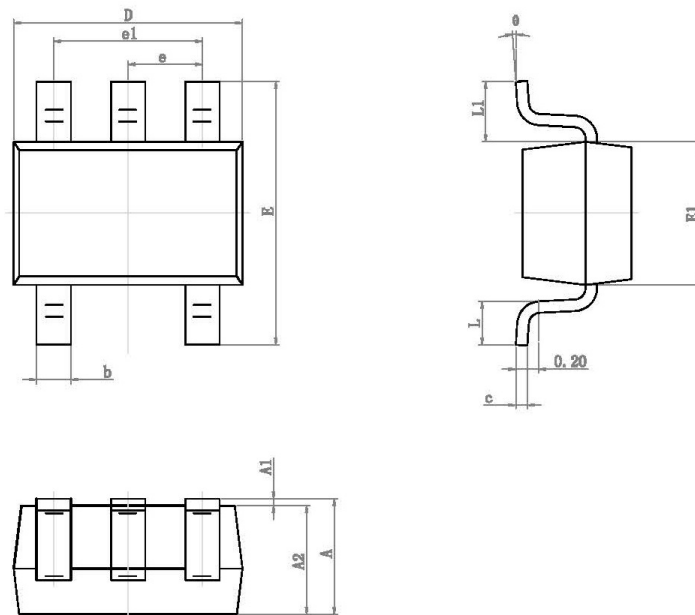


# EM74LVC1G14

Single Schmitt trigger inverter

SOT353

## SOT-353 (16R) PACKAGE OUTLINE DIMENSIONS

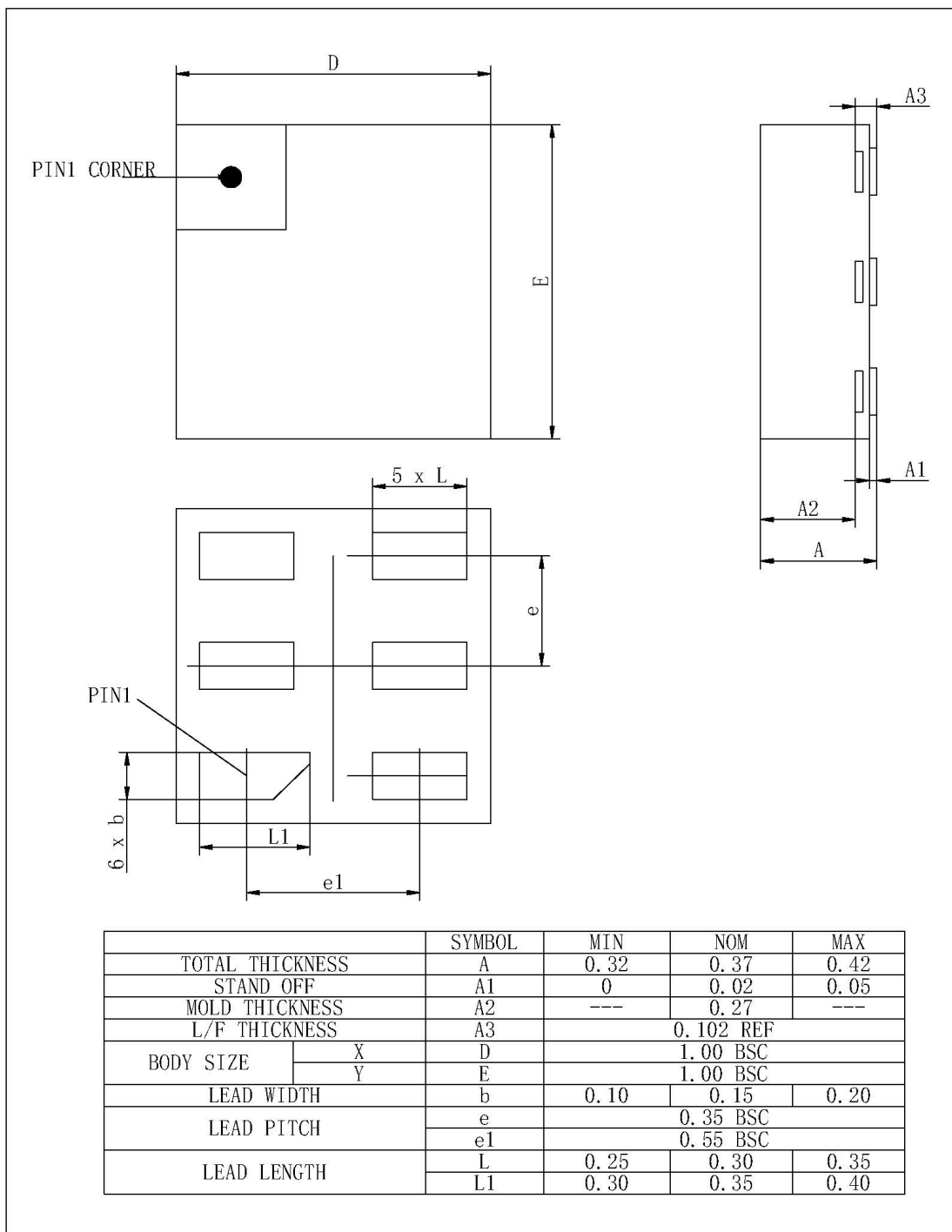


| Symbol | Dimensions In Millimeters |       | Dimensions In Inches |       |
|--------|---------------------------|-------|----------------------|-------|
|        | Min.                      | Max.  | Min.                 | Max.  |
| A      | 0.900                     | 1.100 | 0.035                | 0.043 |
| A1     | 0.000                     | 0.100 | 0.000                | 0.004 |
| A2     | 0.900                     | 1.000 | 0.035                | 0.039 |
| b      | 0.150                     | 0.350 | 0.006                | 0.014 |
| c      | 0.110                     | 0.175 | 0.004                | 0.007 |
| D      | 2.000                     | 2.200 | 0.079                | 0.087 |
| E      | 2.150                     | 2.450 | 0.085                | 0.096 |
| E1     | 1.150                     | 1.350 | 0.045                | 0.053 |
| e      | 0.650 TYP.                |       | 0.026 TYP.           |       |
| e1     | 1.200                     | 1.400 | 0.047                | 0.055 |
| L      | 0.260                     | 0.460 | 0.010                | 0.018 |
| L1     | 0.525 REF.                |       | 0.021 REF.           |       |
| θ      | 0°                        | 8°    | 0°                   | 8°    |

# EM74LVC1G14

Single Schmitt trigger inverter

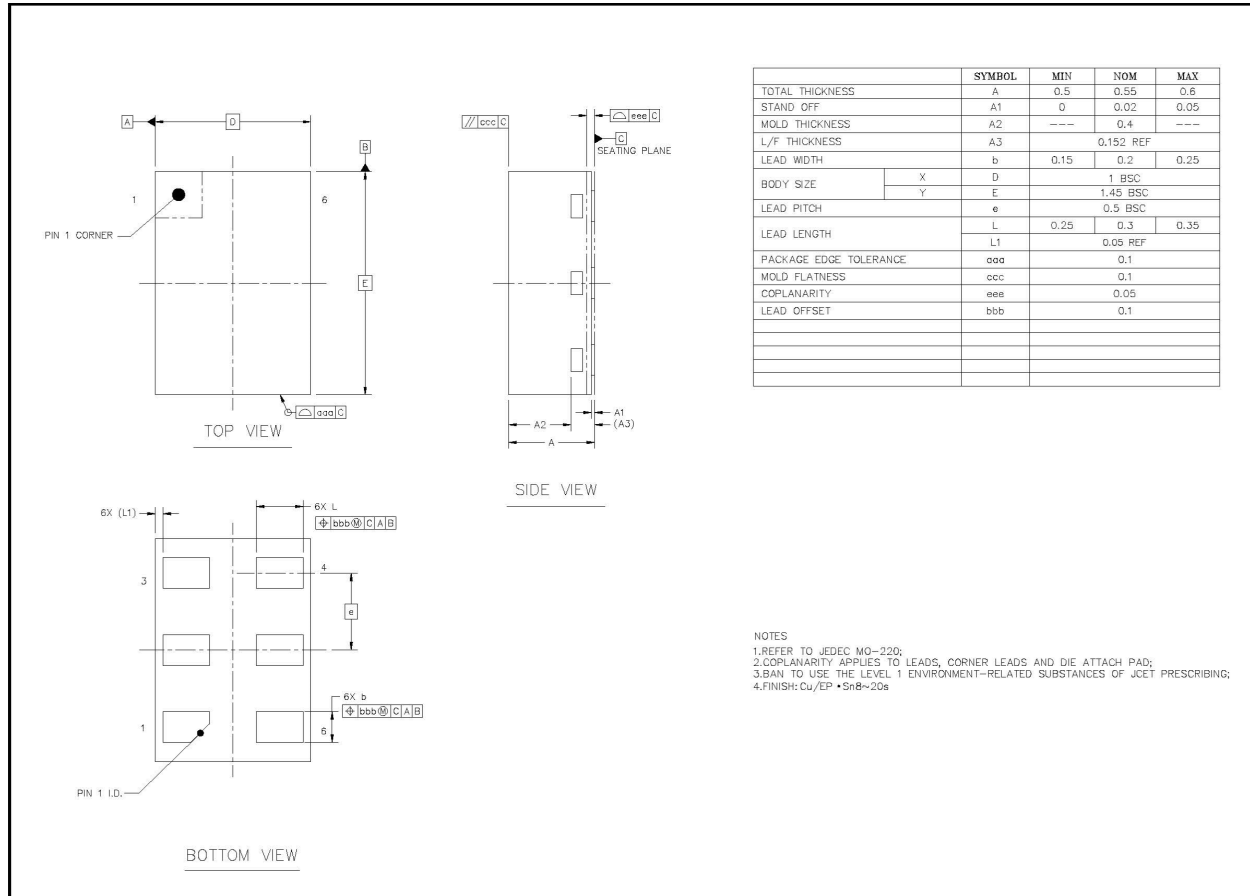
DFN1x1-6L



# EM74LVC1G14

## Single Schmitt trigger inverter

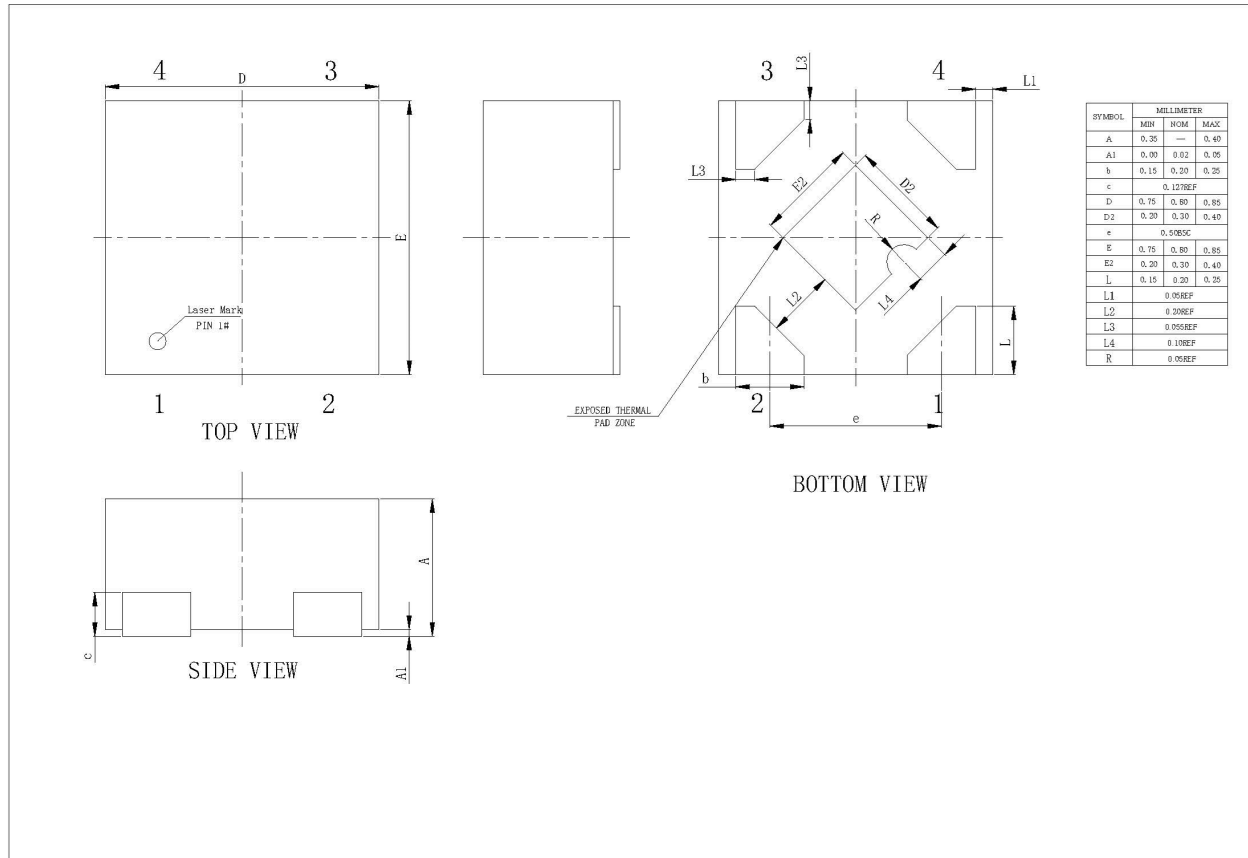
### DFN1x1.45-6L



# EM74LVC1G14

### Single Schmitt trigger inverter

**DFN0.8x0.8-4L**



## 15. Abbreviations

Table 10. Abbreviations

| Acronym | Description                             |
|---------|-----------------------------------------|
| CMOS    | Complementary Metal-Oxide Semiconductor |
| DUT     | Device Under Test                       |
| ESD     | ElectroStatic Discharge                 |
| HBM     | Human Body Model                        |
| MM      | Machine Model                           |
| TTL     | Transistor-Transistor Logic             |

## 16. Revision History

Table 11. Revision history

| Document ID           | Release Date | Data sheet status | Change notice | Supersedes |
|-----------------------|--------------|-------------------|---------------|------------|
| EM74LVC1G14<br>Rev1.0 | Oct 30, 2023 | Product datasheet |               |            |